## **SIEMENS**

# IL388DAA

### **High Peformance Linear Optocoupler** for Optical DAA in Telecommunications

Preliminary

#### **FEATURES**

- 2.3 mm High SMT Package
- High Sensitivity (K1) at Low Operating LED Current
- · Couples AC and DC Signals
- Low Input-Output Capacitance •
- Isolation Voltage, 2500 VDC ٠
- Low Distortion, below -80 db (typical) •
- 0.4 mm Internal Insulation Thickness

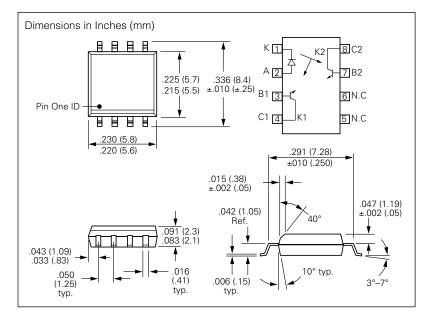
#### APPLICATIONS

- **Optical DAA for V.34 FAX/Modem PCMCIA Cards**
- Digital Telephone Line Isolation

#### DESCRIPTION

The IL388DAA family of Linear Optocoupler consist of an IRLED optically coupled to two photodiodes. The emitter is located such that both photodiodes receive approximately an equal amount of infrared light. The diodes produce a proportional amount of photocurrents. The ratio of the photocurrents stays constant with high accuracy when either the LED current changes or the ambient temperature changes. Thus one can control the output diode current optically by controlling the input photodiode current.

The IL388DAA optocouplers can be used with the aid of operational amplifiers in closed loop conditions to achieve highly linear and electrically isolated AC and or DC signal amplifiers.



#### **Absolute Maximum Ratings**

Emitter	Sym.	Min.	<b>Мах.</b> З	Units
Reverse Voltage	V <sub>R</sub>	<u>                                     </u>		V
Forward Current	IF	—	30	mA
Surge Current Pulse Width <10 $\mu$ s	I <sub>PK</sub>	—	150	mA
Power Dissipation, T <sub>A</sub> =25°C	P <sub>LED</sub>	—	150	mW
Dearate Linearly from 25°C	—	—	2	mW/°C
Junction Temperature	Т_ —		100	°C
Detector (each)				
Reverse Voltage	V <sub>R</sub>	—	15	V
Power Dissipation	Р	—	50	mW
Derate Linearly from 25°C	—	—	0.65	mW/°C
Junction Temperature	TJ		100	°C
Coupler		_		-
Isolation Test Voltage, t=1 sec	VISOL	1768		V <sub>RMS</sub>
Total Package Power Dissipation	Pt	—	250	mW
Derate Linearly from 25°C	—	—	2.8	mW/°C
Storage Temperature	T <sub>S</sub>	-40	150	°C
Operating Temperature	T <sub>OP</sub>	0	75	°C
Lead Soldering Time at 260°C	-		10	sec.
Isolation Resistance $V_{IO}$ =500 V, $T_A$ =25°C $V_{IO}$ =500 V, $T_A$ =100°C	_	$10^{12} \Omega$ $10^{11} \Omega$	_	_

#### Electrical Characteristics (T<sub>A</sub>=25°C)

LED Emitter	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Forward Voltage	V <sub>F</sub>		1.8	2.1	V	I <sub>F</sub> =10 mA
Reverse Current	I <sub>R</sub>		.01	10	μΑ	V <sub>R</sub> =3 V
V <sub>F</sub> Temperature Coefficient	$\Delta V_F / \Delta^\circ C$		-2.2		mV/°C	
Junction Capacitance	CJ		TBD		pF	V <sub>F</sub> =0 V, f=1 MHz
Dynamic Resistance	$\Delta V_{F} / \Delta I_{F}$		6		Ω	
Detector	1	1			1	
Junction Capacitance	CJ		12		pF	V <sub>F</sub> =0 V, f=1 MHz
AC Characteristics Photovoltaic Mode	1	1	L	1		
Frequency Response	BW(–3dB)		1.0		MHz	- I <sub>P1</sub> =25 μA Modulation current ΔIP1=±6 μA
Phase Response			45		Deg.	
Rise Time			350		ns	
Package					I	
Input-Output Capacitance	C <sub>IO</sub>		1		pF	V <sub>F</sub> =0 V, f=1 MHz
Common Mode Capacitance	C <sub>cm</sub>		0.5		pF	V <sub>F</sub> =0 V, f=1 MHz
Coupled Characteristics	1	1	Min.	Тур.	Max.	Units
$K_1$ at I <sub>F</sub> =2 mA, V <sub>D</sub> =0 V		0.007				
THD at $f_0$ =316, I <sub>PI</sub> =35 $\mu$ A, V <sub>D</sub> =0 V		-79			db	
K <sub>3</sub> =K <sub>2</sub> /K <sub>1</sub> , I <sub>F</sub> =2 mA, V <sub>D</sub> =0 V			0.7		1.3	

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